

Trench IGBT Modules

SKM 400GB066D

Features

- Trench = Trenchgate technology
- V_{CE(sat)} with positive temperature coefficient
- High short circuit capability, self limiting to 6 x I_C

Typical Applications*

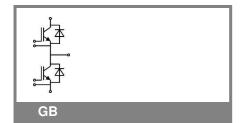
- AC inverter drives
- UPS
- · Electronic welders

Remarks

- Case temperature limited to T_c = 125°C max, recommended T_{op} = -40 ... +150°C
- Product reliability results are valid for $T_i \le 150$ °C
- Short circuit data: $t_p \le 6$ s; $V_{GE} \le 15V$; $T_j = 150^{\circ}C$; $V_{cc} \le 360V$, use of soft R_G necessary !
- Take care of over-voltage caused by stray inductances

Absolute Maximum Ratings T _{case} = 25°C, unless otherwise specified					
Symbol IGBT	Conditions		Values	Units	
V _{CES}	T _j = 25 °C		600	V	
I _C	T _j = 175 °C	T _c = 25 °C	500	Α	
		$T_c = 80 ^{\circ}C$	380	Α	
I _{CRM}	I _{CRM} =2xI _{Cnom}		800	Α	
V_{GES}			± 20	V	
t _{psc}	V_{CC} = 360 V; $V_{GE} \le 15$ V; VCES < 600 V	T _j = 150 °C	6	μS	
Inverse D	iode				
I _F	T _j = 175 °C	$T_c = 25 ^{\circ}C$	450	Α	
		$T_c = 80 ^{\circ}C$	320	Α	
I _{FRM}	I _{FRM} =2xI _{Fnom}		800	Α	
Module					
I _{t(RMS)}			500	Α	
T _{vj}			- 40 + 175	°C	
T _{stg}			- 40 + 125	°C	
V _{isol}	AC, 1 min.		4000	V	

Characteristics T _{ca}		T _{case} =	e = 25°C, unless otherwise specified				
Symbol	Conditions		min.	typ.	max.	Units	
IGBT							
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 6.4$ mA		5	5,8	6,5	V	
I _{CES}	$V_{GE} = 0 V, V_{CE} = V_{CES}$	T _j = 25 °C		0,25	0,75	mA	
V _{CE0}		T _j = 25 °C		0,9	1	V	
		T _j = 150 °C		0,85	0,9	V	
r _{CE}	V _{GE} = 15 V	T _j = 25°C		1,4	2,3	mΩ	
		T _j = 150°C		2,1	3	$m\Omega$	
V _{CE(sat)}	I _{Cnom} = 400 A, V _{GE} = 15 V			1,45	1,9	V	
		$T_j = 150^{\circ}C_{chiplev}$		1,7	2,1	V	
C _{ies}				24,7		nF	
C _{oes}	$V_{CE} = 25, V_{GE} = 0 V$	f = 1 MHz		1,54		nF	
C _{res}				0,73		nF	
Q_G	V _{GE} = -8V+15V			3000		nC	
R _{Gint}	T _j = °C			2		Ω	
t _{d(on)}				200		ns	
t _r	R_{Gon} = 1,5 Ω	$V_{CC} = 300V$		60		ns	
E _{on}	D 450	I _C = 400A		8		mJ	
t _{d(off)}	R_{Goff} = 1,5 Ω	$T_j = 150 ^{\circ}\text{C}$		560		ns	
t _f		$V_{GE} = -8V/+15V$		53		ns	
E _{off}				16		mJ	
R _{th(j-c)}	per IGBT				0,12	K/W	





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Characteristics									
Symbol	Conditions		min.	typ.	max.	Units			
Inverse D	Inverse Diode								
$V_F = V_{EC}$	I _{Fnom} = 400 A; V _{GE} = 0 V	$T_j = 25 ^{\circ}C_{\text{chiplev.}}$		1,4	1,6	V			
V_{F0}		T _j = 25 °C		0,95	1	٧			
r _F		T _j = 25 °C		1,1	1,5	mΩ			
I _{RRM}	I _F = 400 A	T _i = 150 °C		410		Α			
Q_{rr}	di/dt = 7250 A/ s	,		62		С			
E _{rr}	$V_{GE} = -8 \text{ V}; V_{CC} = 300 \text{ V}$			14		mJ			
R _{th(j-c)D}	per diode				0,2	K/W			
Module									
L _{CE}				15	20	nΗ			
R _{CC'+EE'}	res., terminal-chip	T _{case} = 25 °C		0,35		mΩ			
		T _{case} = 125 °C		0,5		mΩ			
R _{th(c-s)}	per module				0,038	K/W			
M_s	to heat sink M6		3		5	Nm			
M _t	to terminals M6		2,5		5	Nm			
w					325	g			

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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z _{th} Symbol	Conditions	Values	Units
$\frac{\mathbf{Z}_{\mathbf{th(j-c)l}}}{\mathbf{R_{i}}}$			
R _i	i = 1	80	mk/W
R _i	i = 2	22,5	mk/W
R _i	i = 3	6,4	mk/W
R _i	i = 4	1,1	mk/W
tau _i	i = 1	0,0447	s
tau _i	i = 2	0,0223	s
taui	i = 3	0,0015	s
tau _i	i = 4	0,0002	s
Z _{th(j-c)D}			<u>.</u>
R _i	i = 1	130	mk/W
Ri	i = 2	55	mk/W
Ri	i = 3	12,5	mk/W
Ri	i = 4	2,5	mk/W
tau _i	i = 1	0,054	s
taui	i = 2	0,01	s
taui	i = 3	0,0015	s
tau _i	i = 4	0,1	s

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